

PRODUCT TYPE	Cryst	al Oscillator HSO321S				
NOMINAL FREQUENCY	8.00000MHz					
H.ELE. SAMPLE O/N		EOS-J70469-1				
H.ELE. P/N	S	SW008000I3CHE-T				
RELEASE DATE	2019/08/01					
VERSION	00					
MSL	Level 1					
PRODUCT STD.	✓ Pb free ✓ R ✓ HF-Halogen	RoHS 2.0 free ☑ REACH Compliant				
	□ AEC-Q100 □ AEC-Q200	(Grade 🗆 0 🗆 1 🗆 2 🖂 3 🗆 4)				
CUSTOMER P/N						
APPLICATION & MODEL						
APPROVED BY CUSTOMER	2					
		(DATE)				

Harmony	Electronic	s Corp.		
			Country of Origin:	Kaohsiung, Taiwan
F. S. TSAI	C. H. WENG	U. F. CHEN		Ratchaburi, Thailand
(APPROVE)	(CHECK)	(PREPARE)		Shenzhen, China
-	- •	-		Dongguan, China



REV. No.	DATE	REASON	REVISE CONTENTS
0	2019/08/01	New	



Contents

ITEM	PAGE
1. CRYSTAL OSCILLATOR SPECIFICATION	3-4
2. DIMENSIONS	4
3. MARKING	5
4. INSIDE STRUCTURE	5
5. HANDLING SUGGESTIONS	5-6
6. EMBOSS CARRIER TAPE&REEL	7-8
7. PACKAGE	8
8. MECHANICAL PERFORMANCE	9
9. ENVIRONMENTAL PERFORMANCE	9
10. APPENDIX	



1. CRYSTAL OSCILLATOR SPECIFICATION

Electrical Specifications

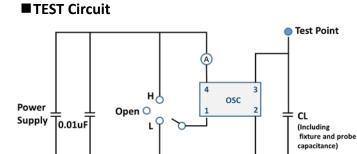
		Ele	ectrical Sp	ec.		
Items	Symbol	Min	Туре	Max	Unit	Condition
Output Frequency	(FL)		8.000000		MHz	
Mode of Oscillation		F	undament	al		
Frequency Stability	Δf/F	-50	-	+50	ppm	@3.3±0.3V/-40~85°C
Operating temp. range	Topr	-40	25	+85	°C	
Supply voltage	Vdd	3.0	3.3	3.6	V	
Pin #1 options				YE	S	
Output load		C-N	105 CL =	15pF (Ido	d1, Idd2 tes	t at No Load)
Current consumption 1 (#1 pin: open or "H")	Idd1	-	-	10	mA	
Current consumption 2 (#1 pin: "L" level)	Idd2	-	-	0.01	mA	
Low level output voltage	Vol	-	-	0.1xVdd	V	
High level output voltage	Voh	0.9xVdd	-	-	V	
Symmetry	Duty	40	50	60	%	
Rise & Fall time	Tr & Tf	-	-	7	ns	
Low level input current	lil	-	-	10	uA	@3.3V/ 25±3°C
High Level input current	lih	-	-	10	uA	
Low level input voltage	Vil	-	-	Vddx0.3	V	
High level input voltage	Vih	Vddx0.7	-	-	V	
Output disable time	Tplz	-	-	150	nsec	
Output enable time	Tpzl	-	-	10	msec	
Aging	-	-3	-	3	ppm/year	
Start-up time		-	-	10	ms	
Jitter, Phase	RMS(1-σ)	-	-	1	ps	12KHz~20MHz Frequency Band

Note: Storage Temperature is only for the product itself.

■ Absolute Maximum Ratings

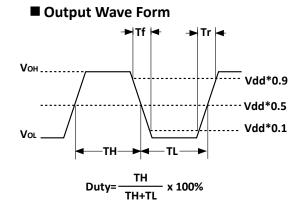
Item	Symbol	Value	Unit
Vdd terminal voltage	Vdd	-0.5 ~ 4.0	V
Input terminal voltage	Vcont	-0.5 ~ Vdd+0.5	V
Output terminal voltage	Vout	-0.5 ~ Vdd+0.5	V
Output terminal current	lout	15	mA
Storage temp. range	Tstr	-55 ~ 125	deg.C

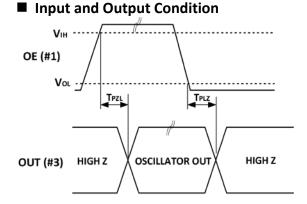




CL = Include jig & probe capacitance (Refer to 4)

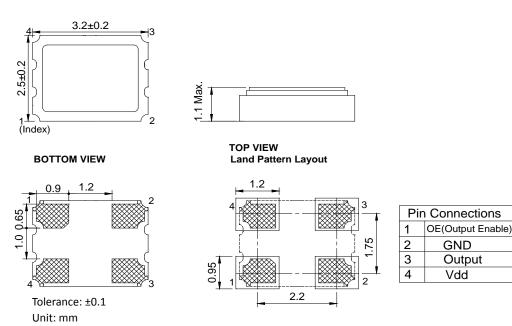
Switch	Out term.
Н	Oscillation out
Open	Oscillation out
L	High Z





2. DIMENSION

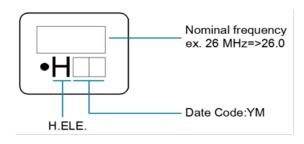
TOP VIEW



* Note: The Index mark was defined by the BASE suppliers.







Note:

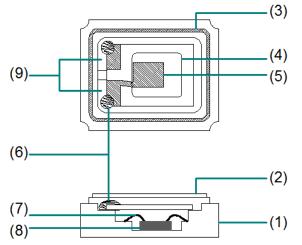
1. Laser marking.

2. Date Code:

V. Voor	2010	2011	2012	2013	2014	2015	2016	2017	2018	2019
Y= Year	2020	2021	2022	2023	2024	2025	2026	2027	2028	2029
Code	0	1	2	3	4	5	6	7	8	9

M= Month	Jan.	Feb.	Mar.	Apr.	May.	Jun.	Jul.	Aug.	Sep.	Oct.	Nov.	Dec.
Code	А	В	С	D	E	F	G	Н	J	К	L	М

4. INSIDE STRUCTURE



Reference drawing

No.	Component	Material	Note
1	Base-Ceramic	Ceramic	Al ₂ O ₃
2	Lid	Fe- Ni -Co	Fe- Ni -Co
3	Kovar	Fe-Ni-Co	Fe-Ni-Co
4	Crystal Blank	Metal	SiO₂ Rectangular At-Cut
5	Electrode	Metal	-
6	Connective Adhesive	Silver Powder	Ag
7	Bonding Wire	Metal	Au
8	IC	Silicon	Si, Al
9	Pad	Metal	W Ni-Plating Au-Plating

%The use prohibition chemistry substance of Table 1 of DHE-0204-1 (HE-QA-24) is not included in this item.

5. HANDLING SUGGESTION

Reflow Condition

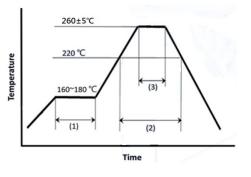
Please stay with our proposed reflow condition and do soldering within 2 times.

(1) Preheat 160~180deg C 120 sec

(+)	Teneut	100 10	oucs.c	120 300.
(2)	Primary heat	>=220	deg.C	100±20 sec.
(3)	Peak	260±5	deg.C	10 sec. Max.

Manual Solder iron (Example)

Bit temp.: 350° C max., Time: 3sec max., Each terminal only should be soldered once.





Mounting Conditions

Our products are suitable for most automated SMT processes. However, we strongly advise all our customers to conduct SMT sampling prior to mass production in order to make sure production processes will not affect the properties and specifications of our product. Seal welding and mounting procedures involving the use of ultra-sonic processes are not recommended and will affect and/or damage the internal properties of our product. Excessive shock during the mounting process will also affect the product and we strongly recommend setting SMT conditions to minimize such conditions.

If a possibility of the PCB being warped exists we strongly advise to ensure the degree of warping will not affect the product.

Please also ensure the operating characteristics and or soldering conditions are all within the specifications of use for our product.

Ultimately the worst case scenario of all the above will lead to cases of non-oscillation but other negative effects are also likely should our products be used in an inappropriate way. Please note such cases of misuse and its related quality issues are not included in our product warranty.

Cleansing Conditions

General cleaning solutions may be used to clean our products but we always recommend testing to be performed prior to mass production processes. Ultrasonic cleaning procedures are not recommended and we strongly advise other forms of cleansing to be evaluated first. Unsuitable cleansing may lead to a number of negative effects such as damage to the product surface, discoloration of the product, corrosion of the package, package contamination, illegible marking, etc. Please note cases of unadvised treatment and its related quality issues are not included in our product warranty.

Storage Conditions

Please ensure our products are preserved appropriately in their original packaging. Irregular environmental instances of moisture will affect our product's stability and may cause problems such as frequency instability, soldering ability and conditions, package defects, and other problems. It is essential to keep our products in a clean dust-free environment out of direct sunlight.

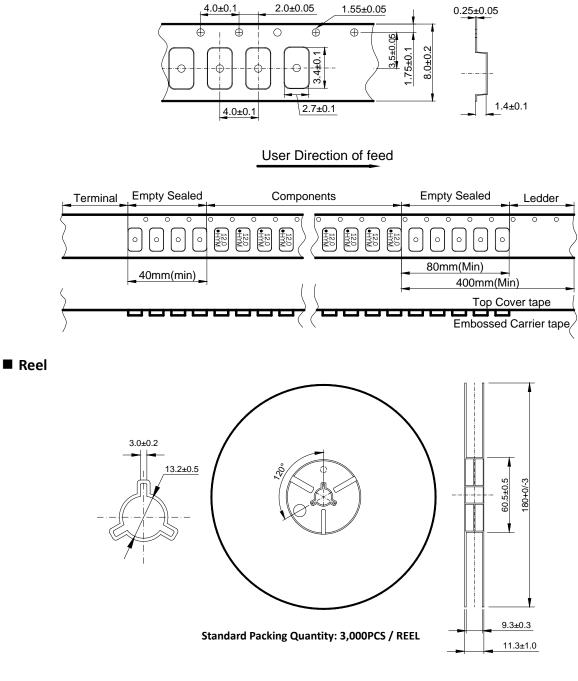
Our products' storage conditions should at least meet the following condition: Environmental Temperature: + 40 degrees Celsius Maximum Relative Humidity: 80% Maximum

Please note storage instances which do not conform to our guidelines and the related quality issues produced as an outcome are not included in our product warranty.



6. EMBOSS CARRIER TAPE AND REEL

Carrier Tape



Material of The Tape

Таре	Material
Carrier tape	PS Conductive
Top tape	PET

Joint of tape

The carrier-tape and top cover-tape should not be jointed.

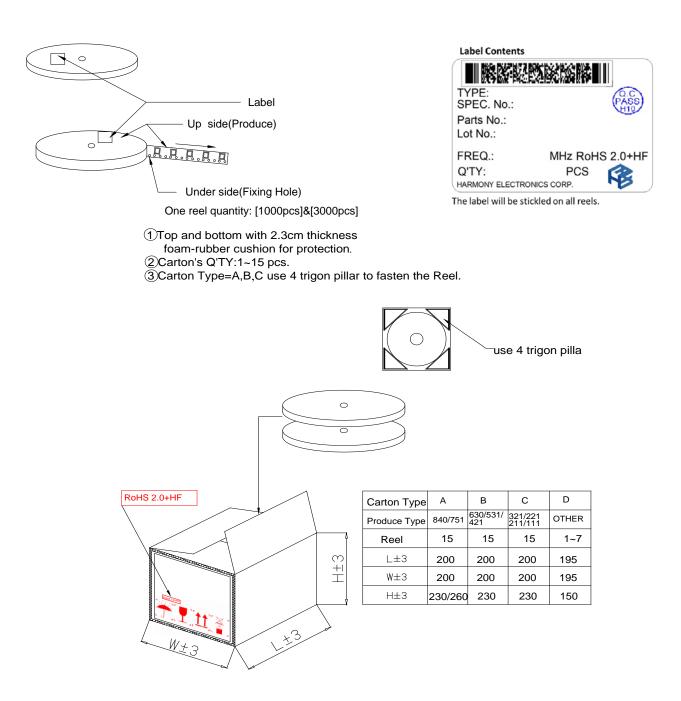


Release strength of cover tape
 The force should be controlled
 between 0.1N to 0.7N under following
 condition.
 Pulling direction: 165° to 180°
 Speed: 300mm/min.
 Otherwise unless specified.



Other standards shall be based on JIS C 0806-1990.

7. PACKAGE





8. MECHANICAL PERFORMANCE

	Item	Test Methods	Specifications Code
1	Shock	Dropping from 50 cm height 3 times on 30mm Concrete Floor. Refer to: JIS C 60068-2-32	А
2	Vibration	Frequency 10-55Hz, Sine Wave full amplitude of 0.8mm to X, Y and Z 3 axes, Duration of 2 hours to each axis. Refer to: JIS C 60068-2-6/MIL-HDBK-781A 6.5.2	А
3	Leakage Test	Leak Rate 1.0x10 ⁻⁹ Pa-m ³ /sec. Max. Measured by Helium leak detector. Refer to: JIS C 60068-2-17	
4	Solder ability	After applying ROSIN Flux, dipping in solder bath at 245deg.C +/- 5deg.C for 3+/-0.5 sec. Refer to: JIS C 60068-2-20/C 60068-2-58	В

9. ENVIRONMENT PERFORMANCE

	Item	Test Methods	Specifications Code
1	Resistance of Soldering Heat	Performing as the following reflow: Refer to: JIS C 60068-2-58	A
2	Humidity	Temperature $60^{\circ}C$ +/-2 $^{\circ}C$, RH 90~95%, Duration of 240 hours. Back to the room temperature first, then check the component after 1~2 hours. Refer to: JIS C 60068-2-3	A
3	Storage in Low Temperature	-40deg.C +/-2deg.C, Duration of 240 hours. Back to the room temperature first, then check the component after 1~2 hours. Refer to: JIS C 60068-2-1	A
4	Storage in High Temperature	+85deg.C +/-2deg.C, Duration of 240 hours. Back to the room temperature first, then check the component after 1~2 hours. Refer to: JIS C 60068-2-2	А
5	Thermal shock	 -40deg.C +/-2deg.C (30min) ↔ +85deg.C +/-2deg.C (30min) 25 cycles. And Temperature Increasing/reducing time ≤ 3mins. Back to the room temperature first, then check the component after 1~2 hours. Refer to: JIS C 0025 	A

Specifications code	Specifications
Α	Frequency variation shall be within +/-5ppm
В	More than 90% of lead shall be covered by new solder.

FACTORY LOCATION

HEAD OFFICE/TAIWAN FACTORY

NO.39, HUADONG RD., DALIAO DIST., DAFA INDUSTRIAL PARK, KAOHSIUNG CITY 831.

CHINA FACTORY

SHEN ZHEN JU YUAN INDUSTRIAL PARK, QIAO TANG ROAD, TANG WEI COMMUNITY, FUYONG, BAOAN DISTRICT, SHEN ZHEN CITY (Post Code:518103).

DONGGUAN BUILDING A1, HUAZHI INDUSTRIAL PARK, NO.38, JINGFU EAST ROAD, DALANG TOWN, DONGGUAN CITY.

THAILAND FACTORY

66MOO 5, KAONGU-BEOKPRAI RD., T.BEOKPRAI, A. BANPONG, RATCHABURI PROVINCE 70110.

SERVICE CENTER

TAIPEI OFFICE

2F., NO.409, SEC.2, TIDING BLVD., NEIHU DISTRICT, TAIPEI CITY 114, TAIWAN TEL: 886-2-26588883 FAX: 886-2-26588683

CONTACT INFORMATION

E-MAIL: contactus@hele.com.tw

